### MITSUBISHI<Dig.Ana.INTERFACE>

# M62001L,FP/M62002L,FP/M62003L,FP/M62004L,FP/ M62005L,FP/M62006L,FP/M62007L,FP/M62008L,FP

## LOW POWER 2 OUTPUT SYSTEM RESET IC SERIES

## DESCRIPTION

The M62001~8 are semiconductor integrated circuits whose optimum use is for the detection of the rise and fall in the power supply to a microcomputer system in order to reset or release the microcomputer system.

The M62001~8 carry out voltage detection in 2 steps and have 2 output pins.As Bi-CMOS process and low power dissipating circuits are employed, they output optimum signals through each output pin to a system that requires RAM backup, As output signals, interruption(INT) and compulsive reset(RESET) signals are available. The interruption signal(INT) is used to alter the microcomputer from normal mode to backup mode and vice versa. these output signals are classified into pulse type(M62001~M62004) and hold type (M62005~M62008).

## FEATURES

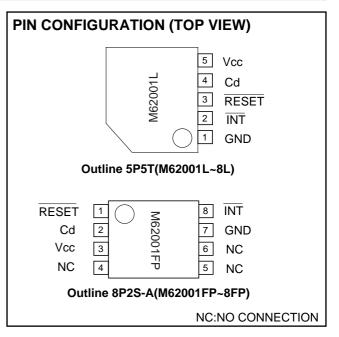
 Bi-CMOS process realizes a configuration of low current dissipating circuits.

Circuit current Icc=5µA(Typ.,normal mode,Vcc=5.0V) Icc=1µA(Typ.,backup mode,Vcc=2.5V) •Two-step detection of supply voltage Detection voltage in normal mode (2 types) Vs=4.45V/4.25V(Typ.) Detection voltage in backup mode VBATT=2.15V(Typ.)

•Two outputs

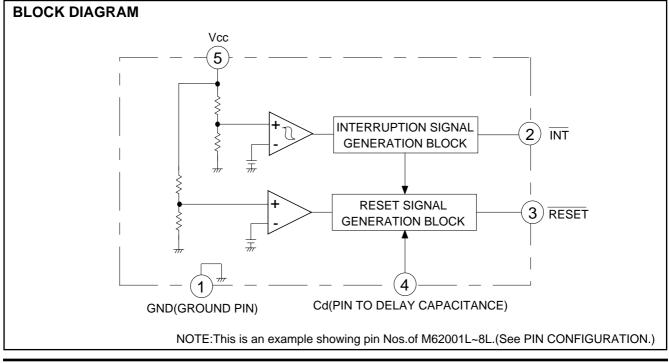
- Reset output (RESET):Output of compulsive reset signal Interruption output(INT):Output of interruption signal •Two types of output forms:CMOS and open drain
- •Two types of interruption output (INT) signals Pulse type (M62001~M62004)
  - Hold type (M62005~M62008)
- •Two types of outline packages
- 5-pin plastic SIP (single in-line package) 8-pin plastic SOP (mini flat package)

•Output based on RAM backup mode (See the timing chart.)



### APPLICATION

Prevention of malfunction of microcomputer systems in electronic.equipment such as OA equipment, industrial equipment, and home-use electronic appliances.





### ABSOLUTE MAXIMUM RATINGS

(Ta=25°C, unless otherwise noted, These ratings commonly apply to the M62001L/FP~M62008L/FP.)

Symbol	Parameter	Conditions	Ratings	Unit
Vcc	Supply voltage		8	V
ISINK	Output sink current		5	mA
Pd	Power dissipation		440	mW
Ke	Thermal derating	(Ta 25°C)	4.4	mW/°C
Topr	Operating temperature		-20 ~ +75	°C
Tstg	Storage temperature		-40 ~ +125	°C

#### **ELECTRICAL CHARACTERISTICS**

(Ta=25°C, unless otherwise noted, These ratings commonly apply to the M62001L/8L.)

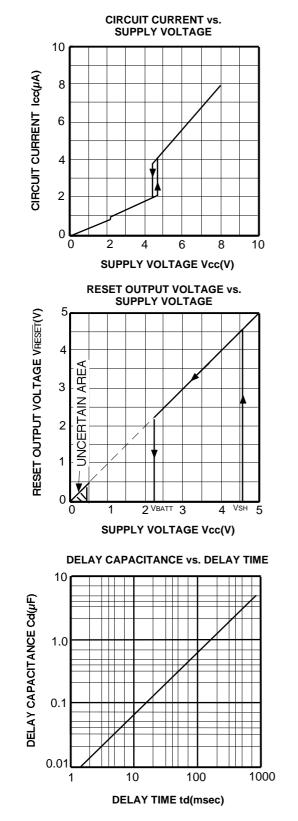
Symbol	Parameter	Test conditions		Limits			Unit
				Min.	Тур.	Max.	Unit
Vs	Supply voltage	Interruption level during Vcc drop (Equivalent to VsL)	(M62001,M62002, M62005,M62006)	4.30	4.45	4.60	V
			(M62003,M62004, M62007,M62008)	4.05	4.25	4.45	
Vbatt	Battery voltage	Reset level at backup	Reset level at backup		2.15	2.30	V
Vs	Hysteresis voltage	Vs=VsH-VsL	Vs=VsH-VsL		100		mV
lcc	Circuit current	Vcc=5.0V:In normal mode			5.0	20	μA
ICC		Vcc=2.5V:In backup mode			1.0	4	
Vsat1	Sink ability	Vcc=4V,Io=4mA (Output saturation voltage of N-ch transistor)			0.2	0.4	V
Vsat2	Source ability	Vcc=4V,Io=1mA (Output saturation voltage of P-ch transistor: [CMOS output] M62001,M62003, M62005,M62007)			0.2	0.4	V
td	Delay time	External capacitance Cd=0.33µF			50		ms
tpw	Pulse width	Output pulse width (M62001,M62002, M62003,M62004)			7	10	μS
tRESET	Reset output response time	Time between Vcc(when falling)=VBATT and output of RESET signal			30		μS
tINT	Interruption output reset time	Time between Vcc(when falling)=Vs and output of INT signal			100		μS

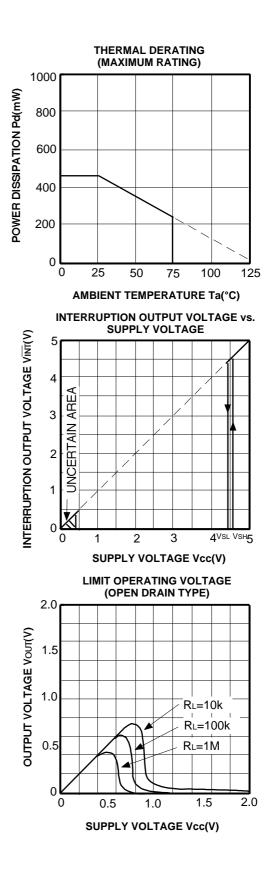
#### SUMMARY OF M62001L/FP~M62008L/FP

Туре	Supply voltage detection level Vs(V)	Battery voltage detection level VBATT(V)	Output form	Interruption signal output mode
M62001	4.45		CMOS	Pulse output
M62002	4.45		Open drain	
M62003	4.05	2.15	CMOS	▁
M62004	4.25		Open drain	
M62005	4.45		CMOS	Hold output
M62006	4.45		Open drain	
M62007	- 4.25		CMOS	╡ <u></u>
M62008	4.23		Open drain	

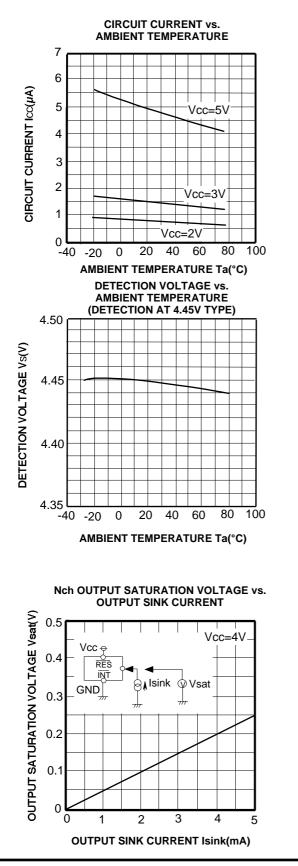


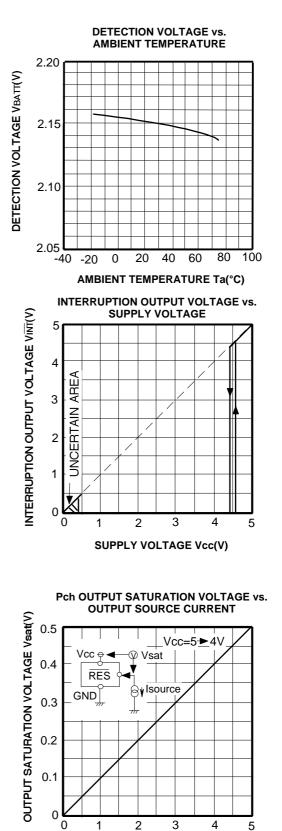
## **TYPICAL CHARACTERISTICS**









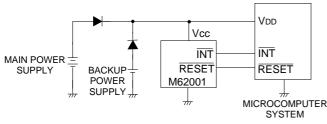


OUTPUT SOURCE CURRENT Isource(mA)



#### OPERATION PRINCIPLE DESCRIPTION

In general,the memory backup function of a microcomputer,as shown in figure,uses two diodes to switch between main power supply and backup power supply.The M62001~M62008 are ICs that,in such memory backup operation,monitor in 2 steps each voltage on the VDD line.



The ICs have an intelligent sequence such as substantial hysteresis action of RESET toward normal state at restoration of supply voltage, as well as 2-step detection in low power dissipation mode.

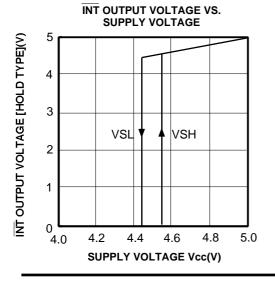
#### OPERATION IN DETAIL 1.Two Step Detection

The ICs perform 2-step detection of supply voltage and have 2 output pins (INT and RESET). Although they have 2 comparators for 2-step detection, they differ significantly from such that are simply provided with independent detectors, because the RESET output signal is dependent at power-up and the like upon the INT output signal.

### 2.INT output (Detection of 4.45V and 4.25V)

The INT output at the power-up of supply voltage detects VSH (4.45V/4.25V)to inform the microcomputer system of the fact that the supply voltage has reached its normal level.When the supply voltage drops from its normal level to VSL(4.45V/4.25V)an interruption signal is output to alter the microcomputer system into RAM backup mode. The microcomputer at this point enters sleep state and secures memory by a stop command issued by the interruption signal.These detection voltage ,VSH the rise,and VSL the fall,of supply voltage,have a 100-mV hysteresis voltage between themselves.

VSH-VSL=100(mV)



### 3. RESET Output (Detection of 2.15V)

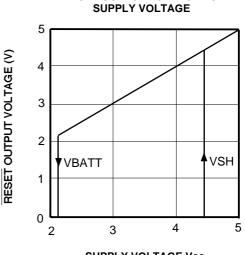
The RESET outputs a signal to prevent the microcomputer from malfunctioning due to a drop in supply voltage. When powering up,RESET is kept at low level until the supply voltage reaches VSH.If the supply voltage rises to VSH,RESET is set to high level.By inserting a capacitor between the Cd pin and GND,it is possible to produce a desired delay time (td).To set a delay time,equation below is used.

### td=1.52X10<sup>5</sup> XCd(sec)

Once the supply voltage has exceeded VSH and the RESET output is set to high level, RESET maintains the high level until the supply voltage drops to VBATT. When the supply voltage drops to VBATT, RESET goes low thereby resetting and initializing the microcomputer.

The RESET output has a large hysteresis voltage of approximately 2V between the rise in supply voltage at powerup and its fall.

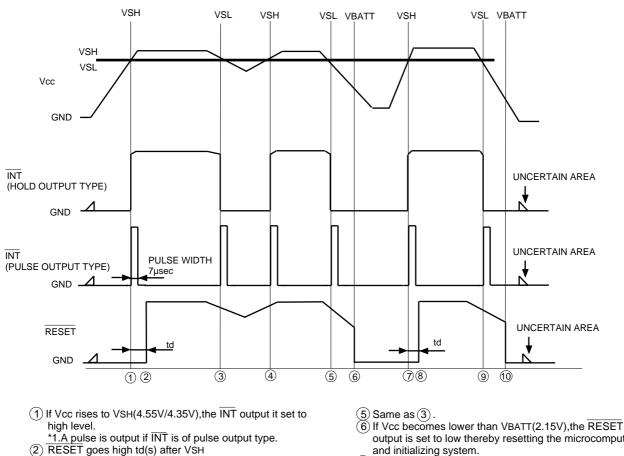
**RESET OUTPUT VOLTAGE VS.** 



SUPPLY VOLTAGE Vcc



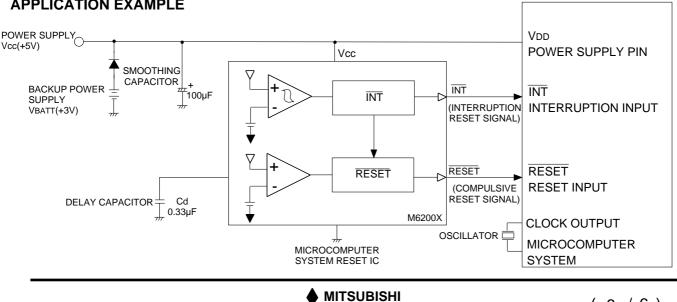
### **OPERATION DESCRIPTION**



- \*td=1.52X105XC(sec)
- (3) If Vcc drops to VSH(4.55V/4.25V), INT goes low. \*1.A pulse is output if INT is of pulse output type.
- \*2.The RESET output continues to be held high.
- (4) If Vcc returns to VSH, the INT output is set to high level.

**APPLICATION EXAMPLE** 

- output is set to low thereby resetting the microcomputer and initializing system.
- Same as (1).
- 8 Same as (2). 9 Same as (3) and (5).
- (10) Same as (6).



ELECTRIC

